



CCLRC  
Daresbury Laboratory

# Front end electronics for the Advanced Implantation Detector Array (AIDA) detector in DESPEC at NUSTAR

Presented by Ian Lazarus

Ian Lazarus  
NPG, CCLRC Daresbury

GSI today

Future facility

100 m

UNILAC

SIS 18

ESR

HESR

SIS 100/300

Super  
FRS

RESR

CR

NESR

NUSTAR

## •Cost

- Approx €1000M
- €650M central German government
- €100M German regional funding
- €250M from international partners

## •Timescale

- Feb 2006- German funds in budget 2007-14
- 2007 start construction
- 2012 phased start experiments
- 2014 completion

# The NUSTAR facility (NUclear STructure Astrophysics and Reactions)

Exotic (radioactive) beams formed by fragmentation, selected by separator.

HiSpec : gamma spec  
DeSpec : decay spec  
LASPEC: laser spec  
MATS: Penning traps



**Pre-Separator**

**Main-Separator**

**High-Energy Branch**

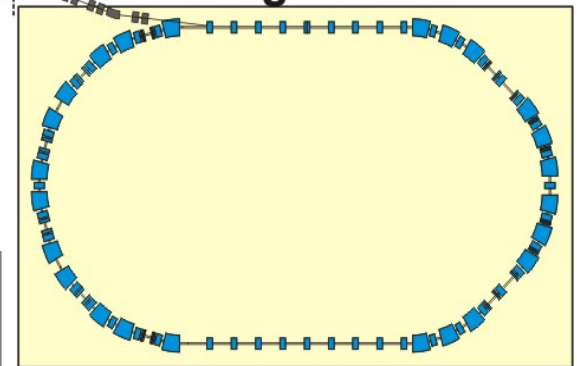
$R^3B$ : reactions

**SIS-200**  
Production Target

100 m

**Ring Branch**

Stored beam (rings):  
EXL : hadron scattering  
ELISE : electron scattering  
AIC : antiproton scattering



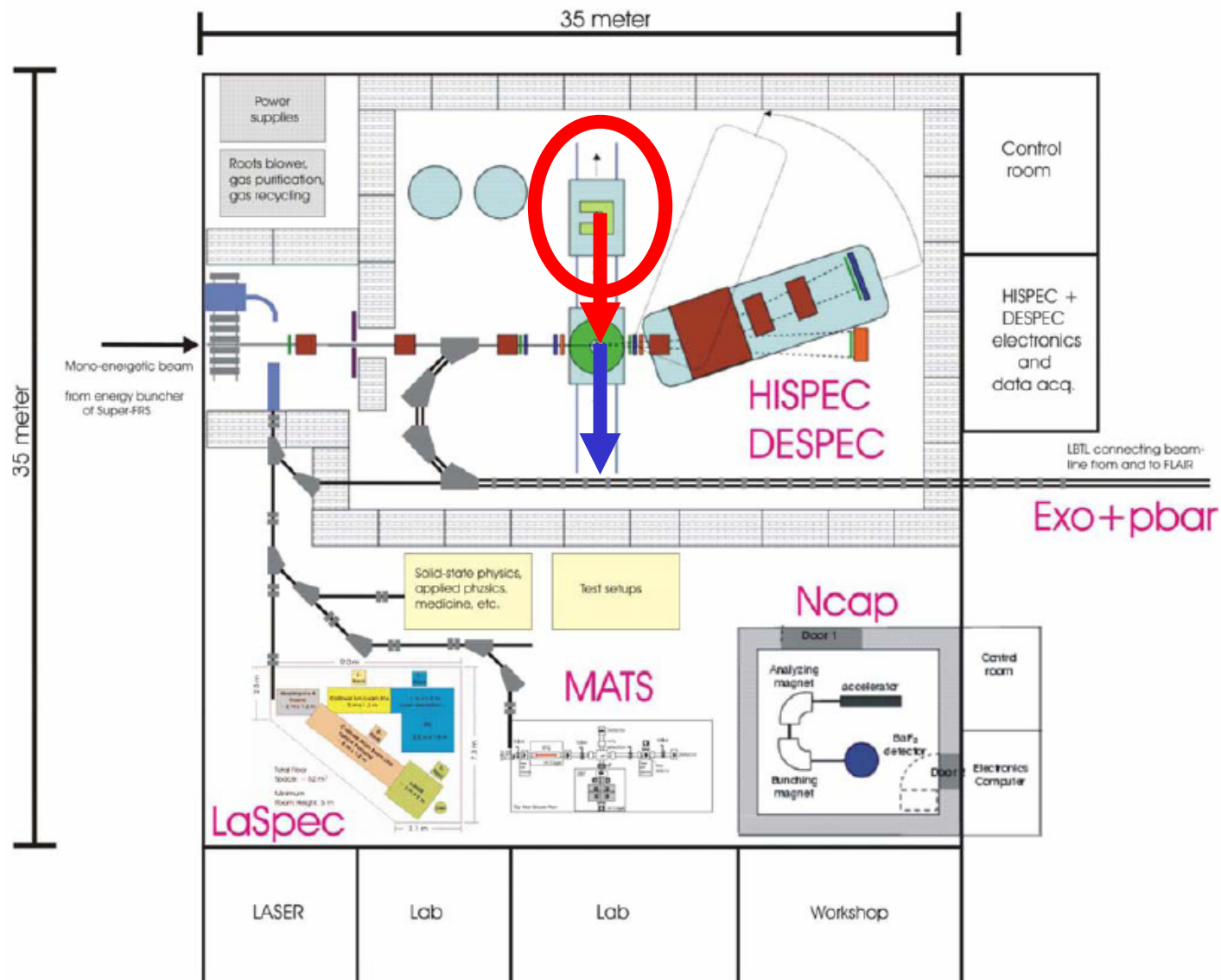
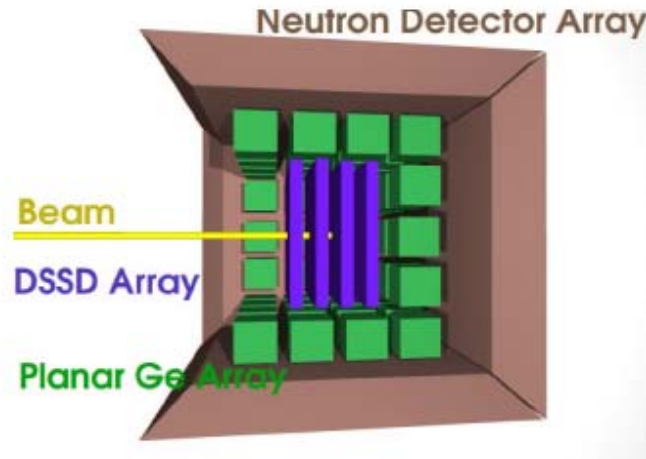


Fig. 1 Overview of the experimental area of the Low-Energy Branch

## Advanced Implantation Detector Array (AIDA)

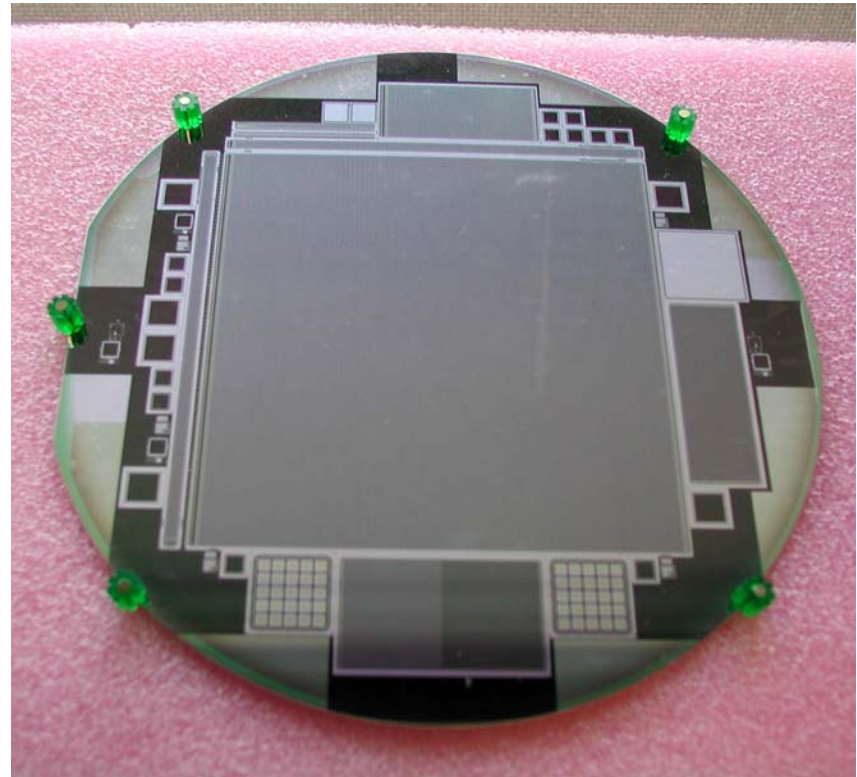
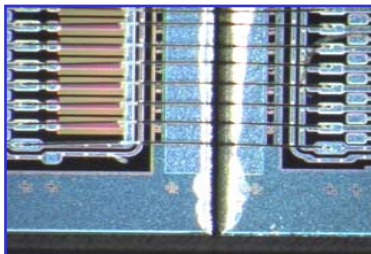


- Super FRS Low Energy Branch (LEB)
- Exotic nuclei – energies  $\sim 50\text{-}150\text{MeV/u}$
- Implanted into multi-plane DSSD array
- Implant - decay correlations
- Multi-GeV DSSD implantation events
- Observe subsequent  $p$ ,  $2p$ ,  $\alpha$ ,  $\beta$ ,  $\gamma$ ,  $\beta p$ ,  $\beta n$  ... decays
- Measure half lives, branching ratios, decay energies ...
- DSSD segmentation ensures average time between implants for given  $x,y$  quasi-pixel  $\gg$  decay half life to be observed.
- Implies quasi-pixel dimensions  $\sim 0.5\text{mm} \times 0.5\text{mm}$

## DSSD

Technology well established  
(e.g. GLAST LAT tracker)

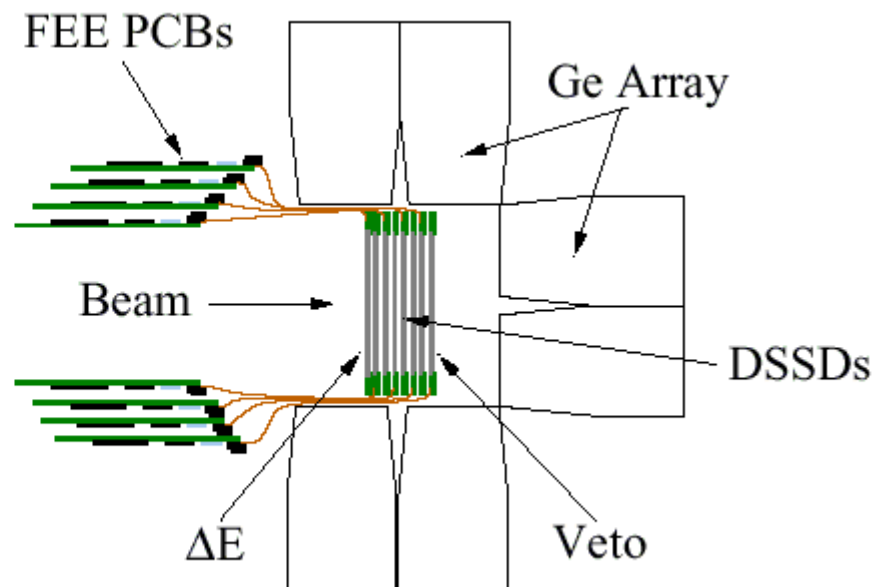
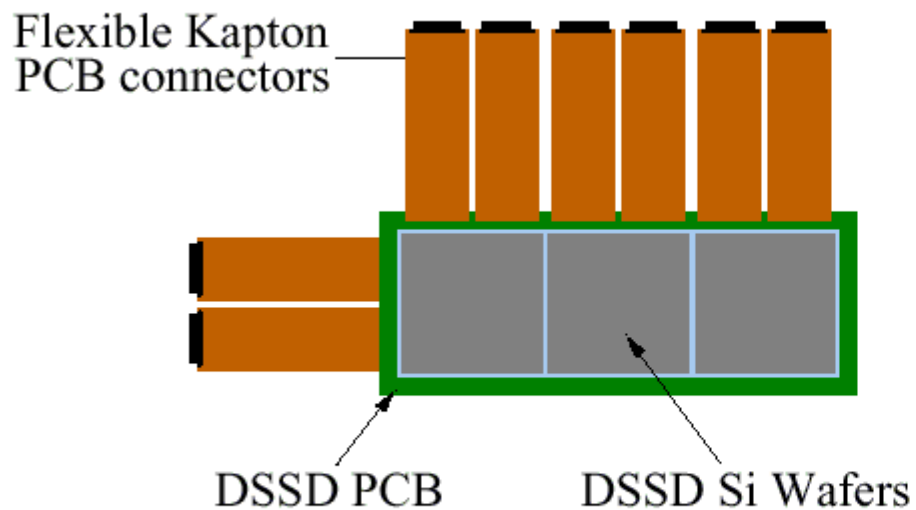
- 6" wafer technology  
10cm x 10cm area
- 1mm wafer thickness
- Integrated components  
a.c. coupling  
polysilicon bias resistors  
... important for ASICs
- Series strip bonding



*8.95 cm square Hamamatsu-Photonics  
SSD before cutting from the 6-inch  
wafer. The thickness is 400 microns,  
and the strip pitch is 228 microns.*

*Slide from Tom Davinson*

## General Arrangement



## Instrumentation

### Why use of Application Specific Integrated Circuit (ASIC) technology?

- Large number of channels required ( $8 \times (128 + (3 \times 128)) = 4096$ )
- Limited available space
- Cost

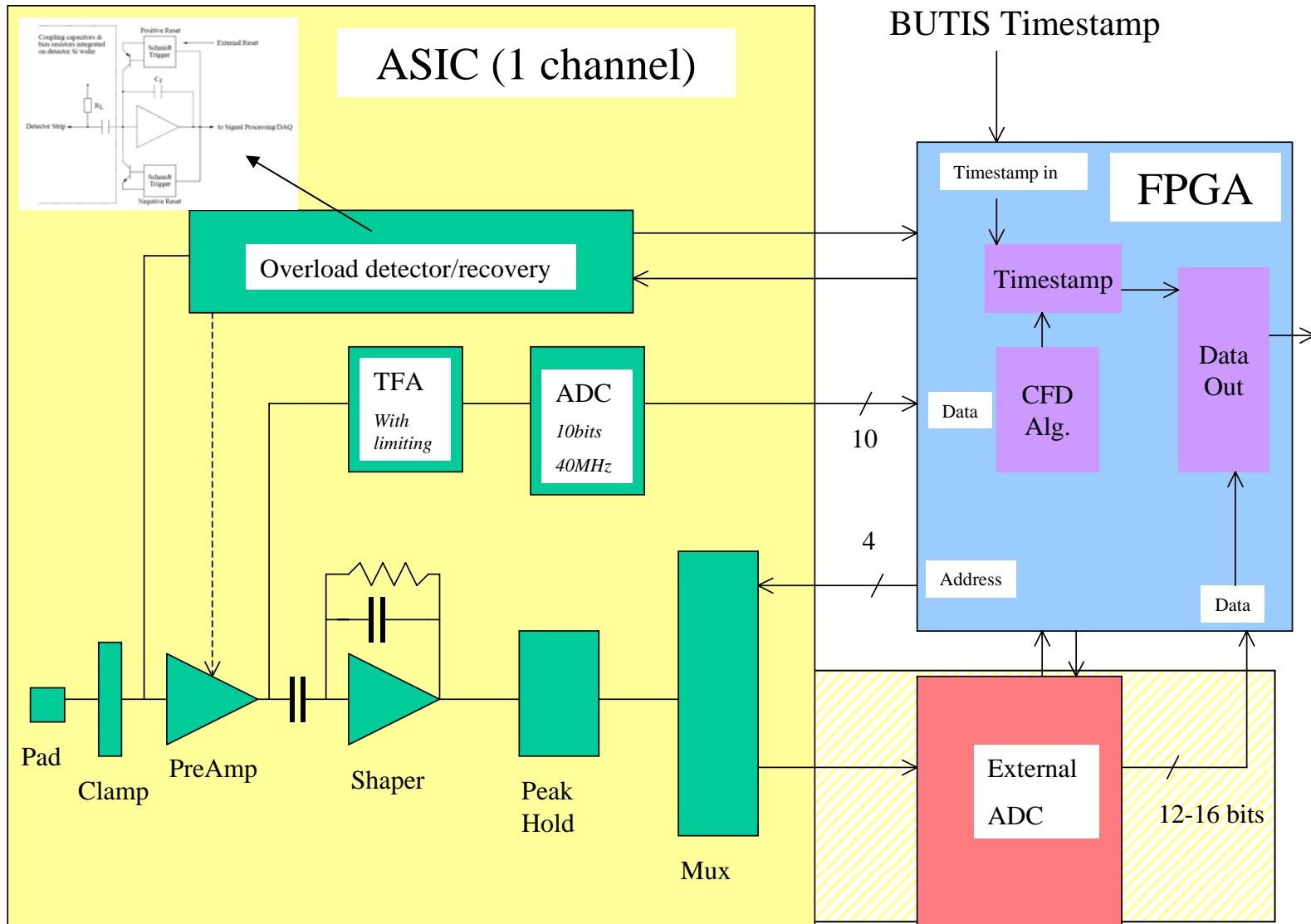
### Outline ASIC Specification

- Selectable gain:      low      20GeV FSR  
                                 high      20MeV FSR
- Noise  $\sigma \sim 5\text{keV rms}$ .
- Selectable threshold: minimum  $\sim 25\text{keV}$  @ high gain ( assume  $5\sigma$  )
- Integral and differential non-linearity
- Autonomous overload recovery  $\sim \mu\text{s}$
- Signal processing time  $< 10\mu\text{s}$  (decay-decay correlations)
- Receive timestamp data
- Timing trigger for coincidences with other detector systems

DSSD segmentation reduces input loading of preamplifier and enables excellent noise performance.

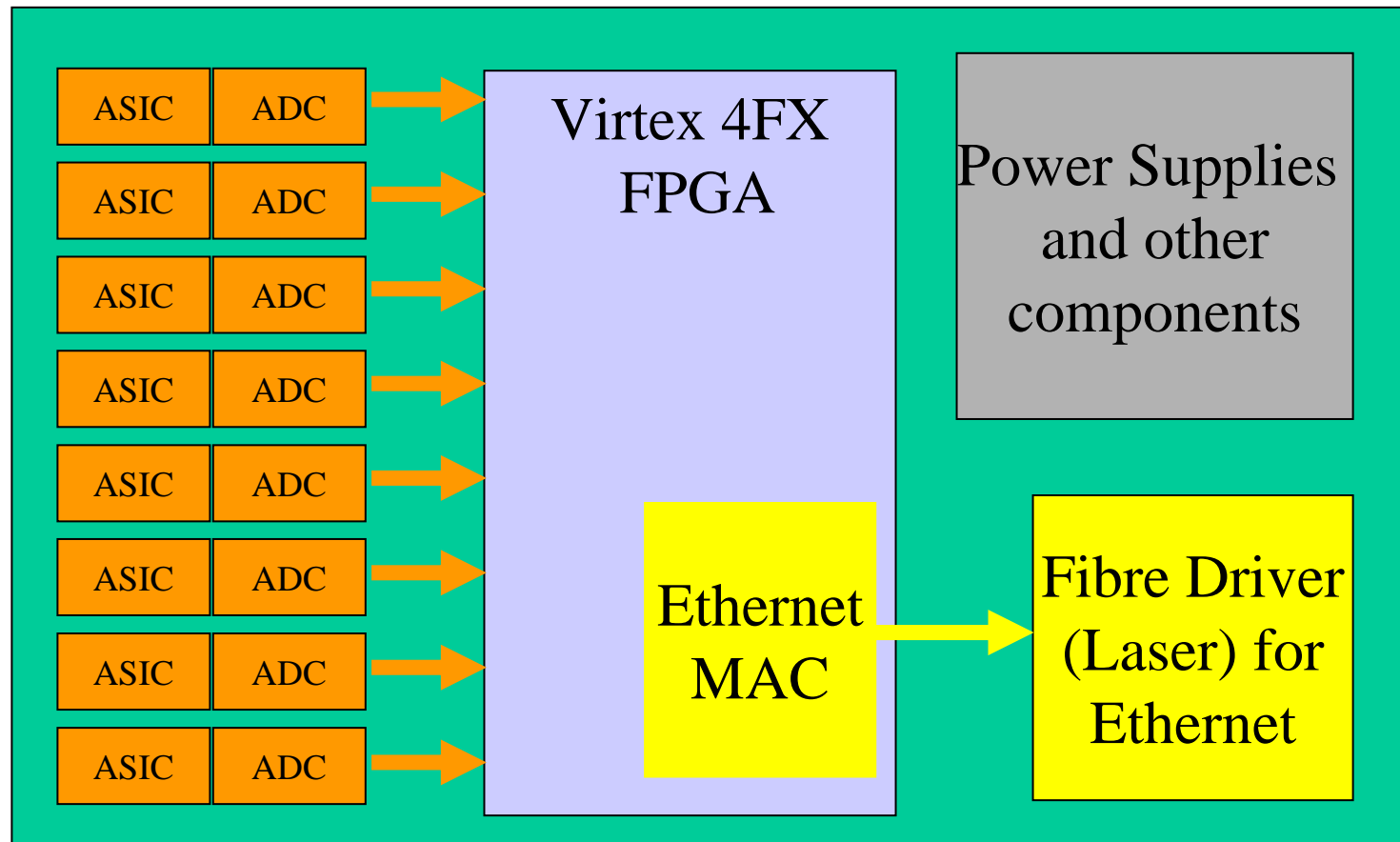
- Problem
  - Multi GeV implant followed by decay in region of 1MeV e.g.  $20\text{GeV}/1\text{MeV} = 2 \cdot 10^4$  dynamic range
- Some possible solutions
  - Logarithmic preamps
    - Makes analysis difficult
  - High/low gain preamp pairs (with clamping)
    - Doubles power, halves packing density
  - Fast recovery from saturation
    - Look at this one first

# 1 of the 16 channels in the DESPEC Implantation Detector ASIC (shown with external FPGA and ADC)

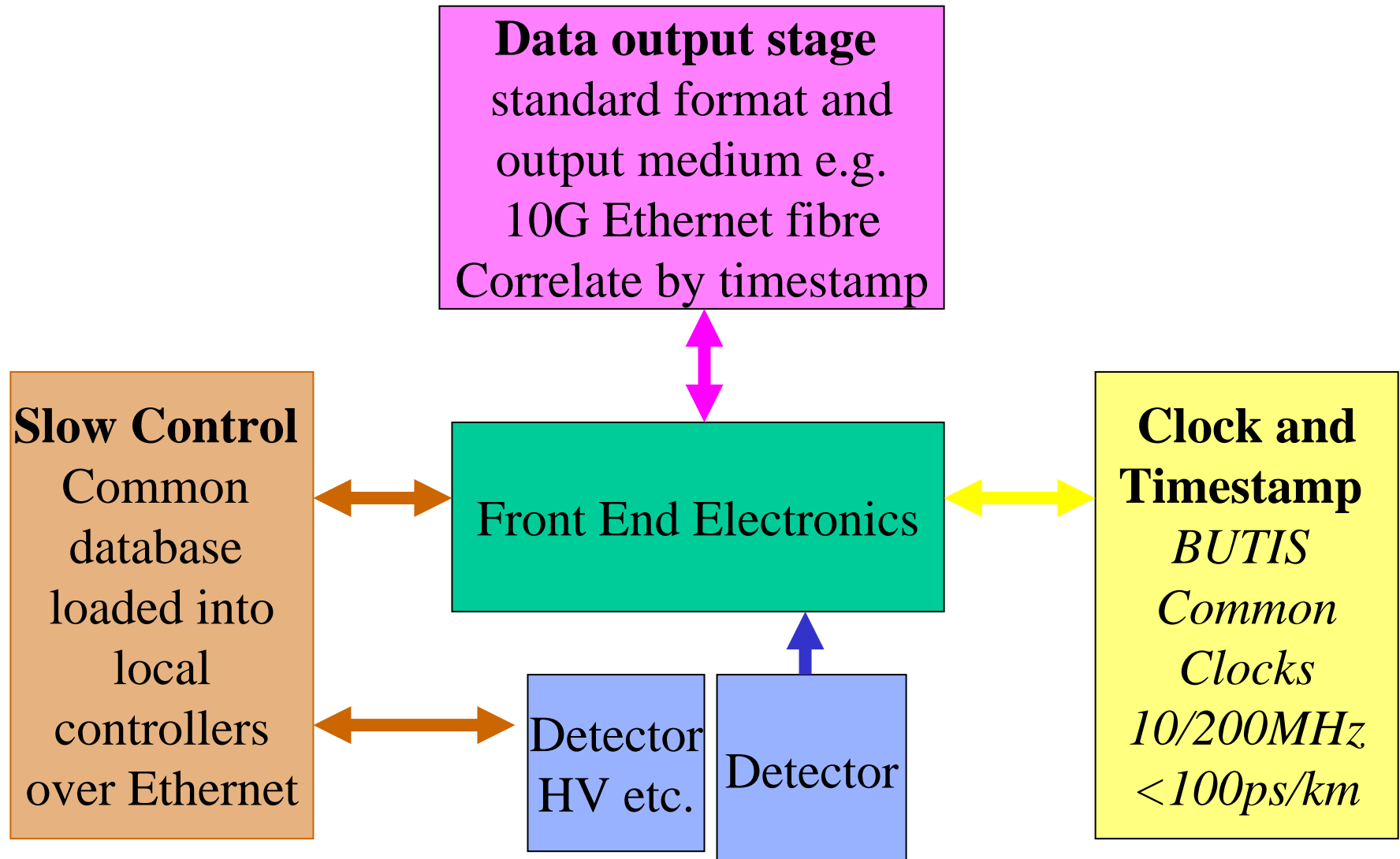


*16 ch ASIC (with ADC?)*

128 detector signals in; 1 data fibre out



Estimated size: 80x220mm,  
Estimated power 25W per 128ch (800W total)



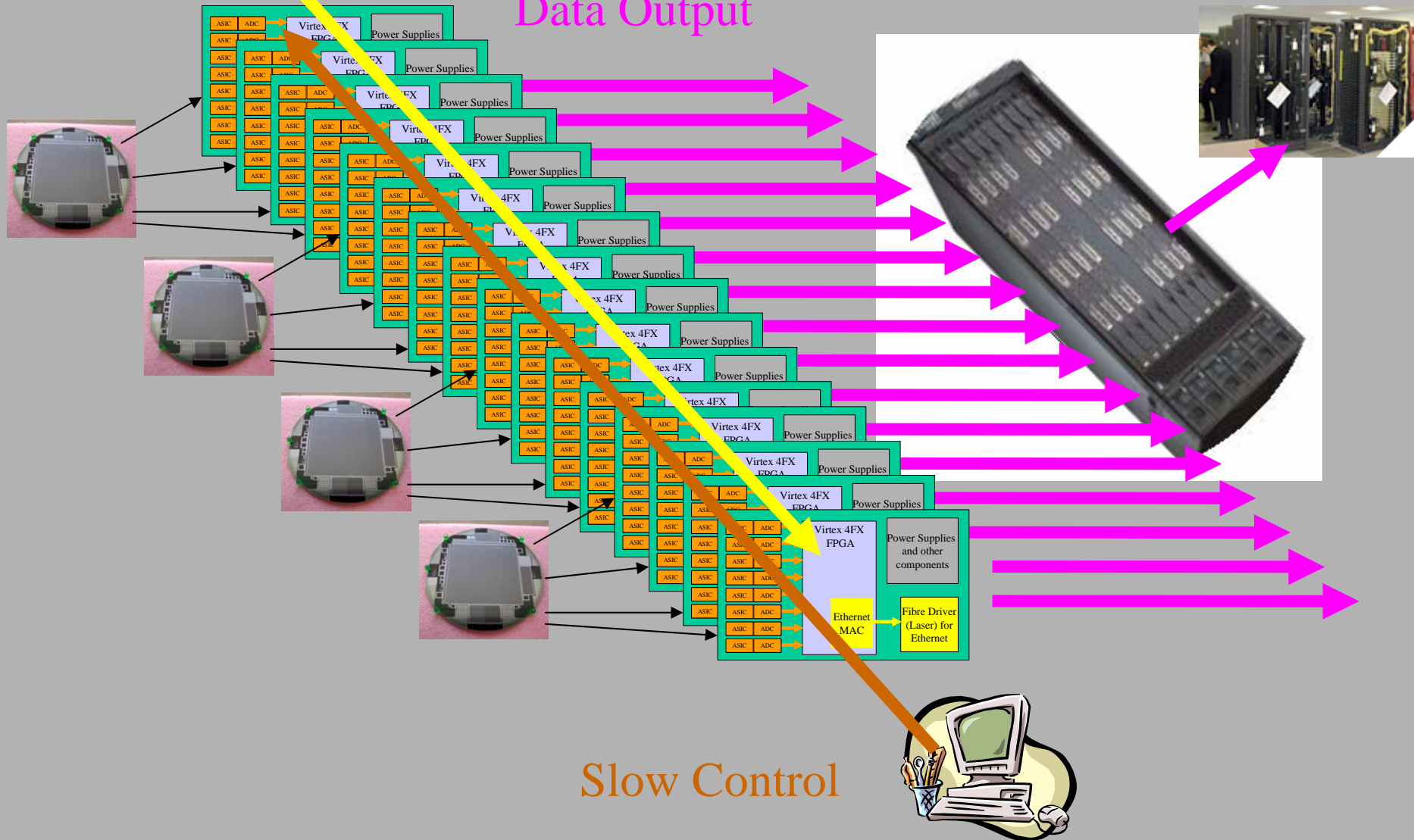
# Diagram of half of AIDA system

BUTIS Timestamps

Data Output

Switch

PC Farm



# The AIDA project- summary

- Objective:
  - To construct a new generation ASIC-based Double-sided Silicon Strip Detector system for decay spectroscopy experiments of exotic nuclei on the new FAIR accelerator facility at GSI, Darmstadt, Germany.
  - To commission and test this system in-beam, and perform ongoing implantation-decay experiments, primarily at GSI, prior to the availability of beams from FAIR.
- 4 years funding from 2006-2010 announced May 2006
- Collaboration:
  - Detectors and project management- University of Edinburgh
  - FEE, ASIC, DAQ - CCLRC
  - Postdoc (detector/physics) Mechanics- University of Liverpool
  - Total 35 – 40 FTE allocated to this project (scientists, engineers, mechanical designers, technicians)